NSN 5962-00-581-4225



Memory Microcircuit - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5962-00-581-4225 **Body Length:** Between 0.660 inches and 0.785 inches **Body Width:** Between 0.220 inches and 0.280 inches **Body Height:** Between 0.140 inches and 0.180 inches **Maximum Power Dissipation Rating:** 176.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and monolithic and positive outputs and w/totem pole output **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** Quad 2 input **Case Outline Source And Designator:** T0-116 joint electron device engineering council **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** -1.5 volts power source and 5.5 volts power source **Memory Device Type:** Rom **Terminal Type And Quantity:** 16 printed circuit Shelf Life: N/a **Unit Of Measure: Demilitarization:**

Yes - demil/mli

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